

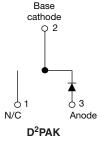
Vishay Semiconductors

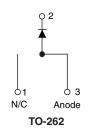
# Ultrafast Rectifier, 30 A FRED Pt®





VS-ETU3006-1-M3

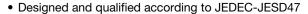




PRODUCT SUMMARY	
Package	TO-263AB (D <sup>2</sup> PAK), TO-262AA
I <sub>F(AV)</sub>	30A
V <sub>R</sub>	600 V
V <sub>F</sub> at I <sub>F</sub>	2 V
t <sub>rr</sub> (typ.)	30 ns
T <sub>J</sub> max.	175 °C
Diode variation	Single die

#### **FEATURES**

- · Low forward voltage drop
- · Ultrafast recovery time
- 175 °C operating junction temperature
- Low leakage current
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition









#### **DESCRIPTION/APPLICATIONS**

Ultralow  $V_F$ , soft-switching ultrafast rectifiers optimized for Discontinuous (Critical) Mode (DCM) Power Factor Correction (PFC).

The minimized conduction loss, optimized stored charge and low recovery current minimized the switching losses and reduce over dissipation in the switching element and snubbers.

The device is also intended for use as a freewheeling diode in power supplies and other power switching applications.

#### **APPLICATIONS**

AC/DC SMPS 70 W to 400 W

e.g. laptop and printer AC adaptors, desktop PC, TV and monitor, games units, and DVD AC/DC power supplies.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	$V_{RRM}$		600	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 113 °C	30	А			
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	200	A			
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		- 65 to 175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-	
Forward voltage V <sub>F</sub>	V	I <sub>F</sub> = 70 A	-	1.4	2.0	V
	v <sub>F</sub>	I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.15	1.35	
Reverse leakage current		V <sub>R</sub> = V <sub>R</sub> rated	-	0.02	30	
neverse leakage current	I <sub>R</sub>	T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	30	250	μΑ
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	20	=	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nH

Document Number: 93592 Revision: 19-Apr-11 For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

#### Vishay Semiconductors Ultrafast Rectifier, 30 A FRED Pt®



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1 A, dI_F/dt = 5$	0 A/μs, V <sub>R</sub> = 30 V	-	30	45	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	45	-	ns
		T <sub>J</sub> = 125 °C		-	100	-	
Dools woods on a commont		T <sub>J</sub> = 25 °C		-	5.6	-	Α
Peak recovery current	IRRM	T <sub>J</sub> = 125 °C		-	10	-	^
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	127	-	- 0
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C	1	-	580	-	nC

THERMAL - MECHANICA	THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 65	-	175	°C		
Thermal resistance, junction to case	R <sub>thJC</sub>		-	0.95	1.4	°C/W		
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	70			
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	-	0.5	-			
Maiabt			-	2.0	-	g		
Weight			-	0.07	-	OZ.		
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)		
Marking dayion		Case style D <sup>2</sup> PAK modified	ETU3006S					
Marking device		Case style TO-262		ETU3	006-1			



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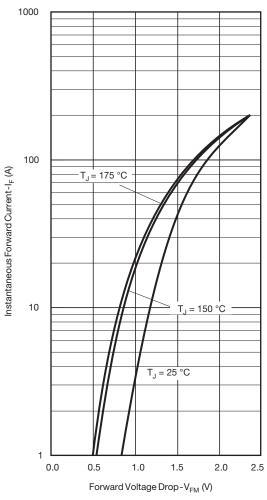


Fig. 1 - Typical Forward Voltage Drop Characteristics

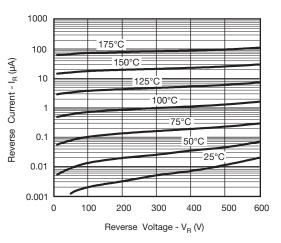


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

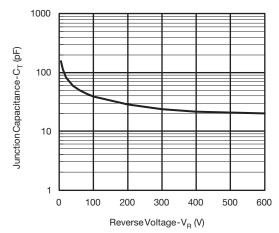


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

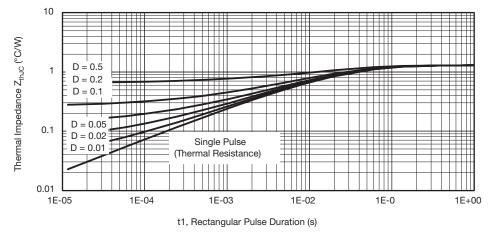


Fig. 4 - Max. Thermal Impedance Z<sub>thJC</sub> Characteristics

#### Vishay Semiconductors Ultrafast Rectifier, 30 A FRED Pt®



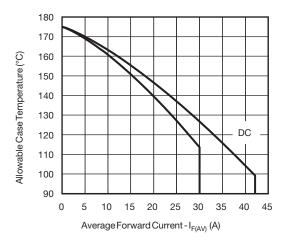


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

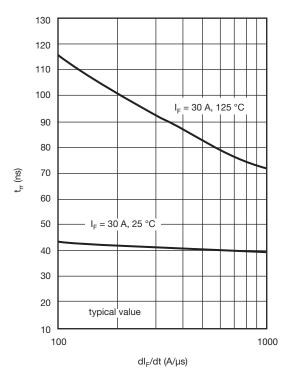


Fig. 7 - Typical Reverse Recovery vs. dl<sub>F</sub>/dt

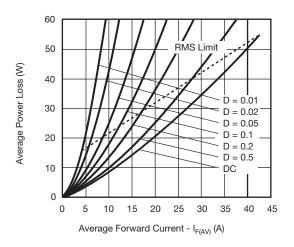


Fig. 6 - Forward Power Loss Characteristics

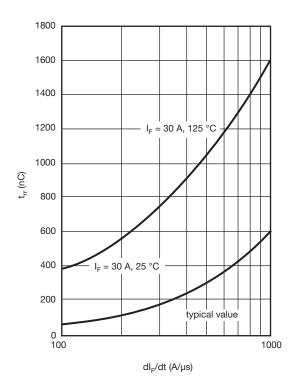


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



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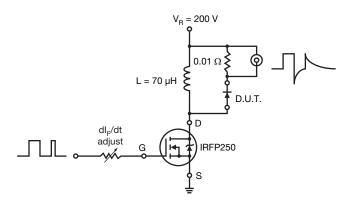
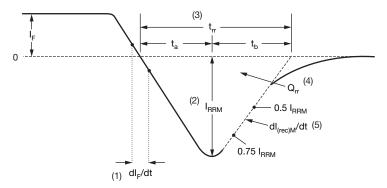


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $t_{rr}$  reverse recovery time measured from zero crossing point of negative going I<sub>F</sub> to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$ extrapolated to zero current.
- (4)  $Q_{rr}$  area under curve defined by  $t_{rr}$ and  $I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

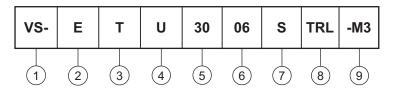
Fig. 10 - Reverse Recovery Waveform and Definitions

Vishay Semiconductors Ultrafast Rectifier, 30 A FRED Pt®



#### **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

Circuit configuration

E = Single diode

T = TO-220

U = Ultrafast recovery time

Current code (30 = 30 A)

Voltage code (06 = 600 V)

•  $S = D^2PAK$ 

• -1 = TO-262

8 • None = Tube (50 pieces)

• TRL = Tape and reel (left oriented, for D2PAK package)

• TRR = Tape and reel (right oriented, for D<sup>2</sup>PAK package)

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free 9

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-ETU3006S-M3	50	1000	Antistatic plastic tube			
VS-ETU3006-1-M3	50	1000	Antistatic plastic tube			
VS-ETU3006STRR-M3	800	800	13" diameter reel			
VS-ETU3006STRL-M3	800	800	13" diameter reel			

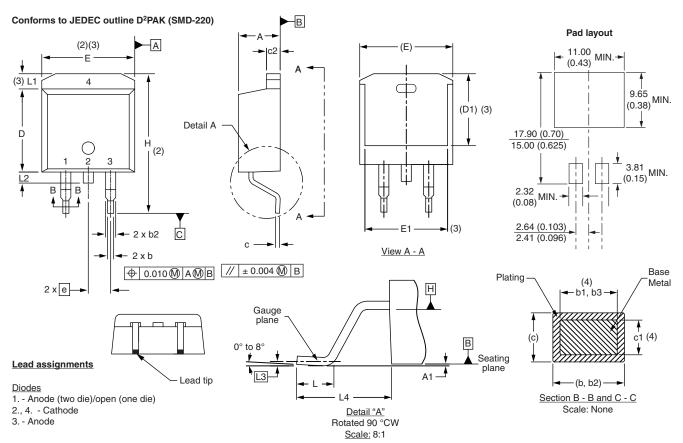
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95046				
Dimensions	TO-262AA	www.vishay.com/doc?95419			
Part marking information	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95444			
Part marking information	TO-262AA	www.vishay.com/doc?95443			
Packaging information	TO-263AB (D <sup>2</sup> PAK)	www.vishay.com/doc?95032			



## Vishay Semiconductors

## D<sup>2</sup>PAK

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIMETERS		INCHES		NOTES	
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100 BSC			
Н	14.61	15.88	0.575	0.625		
L	1.78	2.79	0.070	0.110		
L1	-	1.65	-	0.066	3	
L2	1.27	1.78	0.050	0.070		
L3	0.25	BSC	0.010	BSC		
L4	4.78	5.28	0.188	0.208		

#### Notes

- $^{(1)}$  Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC outline TO-263AB

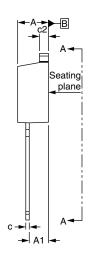


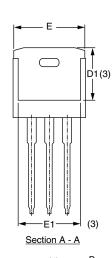
## Vishay Semiconductors

### **TO-262**

#### **DIMENSIONS** in millimeters and inches

# 



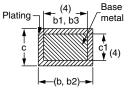


**⊕** 0.010**⋒**|A**⋒**|B

Lead assignments



<u>Diodes</u>
1. - Anode (two die)/open (one die)
2., 4. - Cathode
3. - Anode



Section B - B and C - C Scale: None

CYMPOL	MILLIN	METERS	INC	INCHES	
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	=	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}$  Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000